

No.2823

**DSE015** 

Silicon Epitaxial Type

High-Speed Switching Diode

## **Features**

· Very small-sized package permitting DSE015-applied sets to be made small and slim

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· Fast switching speed

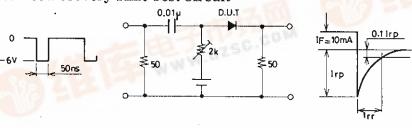
## Absolute Maximum Ratings at Ta = 25°C unit Peak Reverse Voltage -75V $V_{RM}$ Reverse Voltage $V_R$ -- 50 V Surge Current 4 IFSM 1µ sec Average Rectified Current 150 $I_{O}$ mA Peak Forward Current $I_{\text{FM}}$ 300 mA Junction Temperature $^{\circ}C$ Τj 150 Storage Temperature Tstg -55 to + 150°C

## Electrical Characteristics at Ta = 25°C

| llectrical Characteristics at Ta=25°C |                   |   | nin ty | max c | unit |
|---------------------------------------|-------------------|---|--------|-------|------|
| Forward Voltage                       | $V_{\mathbf{F}}$  | $I_F = 10 \text{mA}$  | 0.7    | 2 1.0 | V    |
|                                       |                   | $I_F = 50 \text{mA}$  | 0.8    | 2 1.0 | V    |
|                                       |                   | $I_F = 100 \text{mA}$   | 0.8    | 3 1.2 | V    |
| Reverse Current                       | $I_R$             | $V_R = -50V$  |        | -100  | nΑ   |
| Interterminal Capacitance             | C                 | $V_R = 0, f = 1 MHz$  | 4.     | 5 9   | pF   |
| Reverse Recovery Time                 | $\mathrm{t_{rr}}$ | $I_F = 10 \text{mA}, V_R = -6 \text{V}, R_L = 50 \Omega, I_{rr} = 0.1 \text{Irp}$ |        | 8     | ns   |
| Rated I/O Frequency                   |                   |   |        | 12.5  | MHz  |

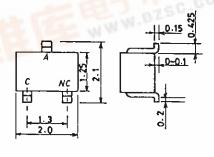
Marking: A1

## Reverse Recovery Time Test Circuit



Package Dimensions 1195 (unit: mm)

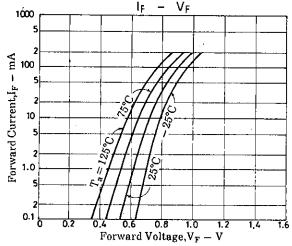
Unit (resistance:  $\Omega$ , capacitance: F)

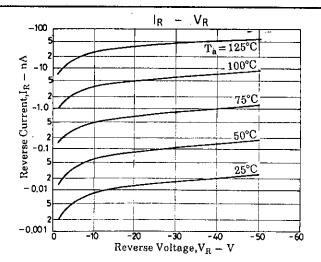


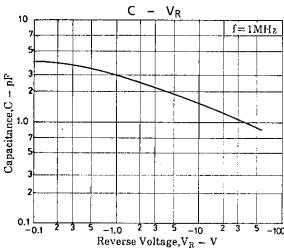


SANYO: MCP C: Cathode

A: Anode







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